

Description

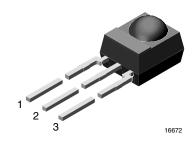
The TSOP7000 is a miniaturized receiver for infrared remote control and IR data transmission. PIN diode and preamplifier are assembled on lead frame, the epoxy package is designed as IR filter.

The demodulated output signal can directly be decoded by a microprocessor. The main benefit is the operation with high data rates and long distances.

This component has not been qualified according to automotive specifications.

Features

- Photo detector and preamplifier in one • package
- Internal Bandfilter for PCM frequency .
- Internal shielding against electrical field • disturbance
- . TTL and CMOS compatibility
- Output active low •
- Small size package
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC . and WEEE 2002/96/EC



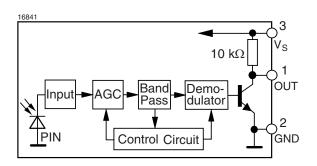
Special Features

- Data rate 20 kbit/s
- Supply voltage 2.7 5.5 V
- · Short settling time after power on
- High envelope duty cycle can be received •
- Enhanced immunity against disturbance from • energy saving lamps

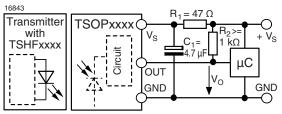
Mechanical Data

Pinning: 1 = OUT, 2 = GND, 3 = V_S

Block Diagram



Application Circuit



 $R_1 + C_1$ recommended to suppress power supply disturbances.

R₂ optional for improved pulse forming.











Absolute Maximum Ratings

 $T_{amb} = 25 \text{ °C}$, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit	
Supply Voltage	Pin 3	V _S	-0.3 to + 6.0	V	
Voltage at output to supply	Pin 1	V _S - V _O	-0.3 to (V _S + 0.3)	V	
Supply Current	Pin 3	۱ _S	5	mA	
Output Voltage	Pin 1	Vo	-0.3 to + 6.0	V	
Output Current	Pin 1	Ι _Ο	15	mA	
Junction Temperature		Tj	100	°C	
Storage Temperature Range		T _{stg}	- 25 to + 85	°C	
Operating Temperature Range		T _{amb}	- 25 to + 85	°C	
Soldering Temperature	$t \le 10$ s, 1 mm from case	T _{sd}	260	°C	
Power Consumption		P _{tot}	30	mW	

Electrical and Optical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Supply Current (Pin 3)	Dark ambient	I _{SD}		2.0	2.7	mA
	E _v = 40 klx, sunlight	I _{SH}		2.3		mA
Supply Voltage (Pin 3)		V _S	2.7	5	5.5	V
Transmission Distance	$λ_p$ = 870 nm, IR Diode TSHF5400, I _F = 300 mA	d _{max}		20		m
	λ_p = 950 nm, IR Diode TSAL6400, I _F = 300 mA	d _{max}		12		m
Threshold Irradiance	$\lambda_p = 870$ nm, optical test signal of fig. 1	E _{e min}		0.8	1.5	mW/m ²
Maximum Irradiance	Optical test signal of fig. 1	E _{e max}	30			W/m ²
Output Voltage Low (Pin 1)	1 k Ω external pull up resistor	V _{QL}			100	mV
Output Voltage High (Pin 1)	No external pull-up resistor	V _{QH}	V _S - 0.25			V
Bandpass filter quality		Q		10		
Out-Pulse width tolerance	Optical test signal of fig.1, 1.5 mW/m ² $\leq E_e \leq 30 W/m^2$	Δ_{tpo}	- 15	+ 5	+ 15	μs
Delay time of output pulse	Optical test signal of fig. 1, $E_e > 1.5 \text{ mW/m}^2$	t _{don}	15		36	μs
Receiver start up time	Valid data after power on	t _V		50		μs
Falling time	Leading edge of output pulse	t _f		0.4		μs
Rise time	No external pull up resistor	t _r		12		μs
	1 k Ω external pull up resistor	t _r		1.2	1	μs
Directivity	Angle of half transmission distance	φ1/2		± 45		deg

Typical Characteristics

 $T_{amb} = 25 \text{ °C}$, unless otherwise specified



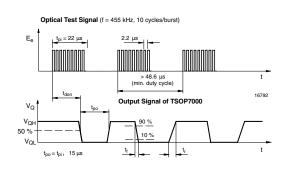


Figure 1. Output Function

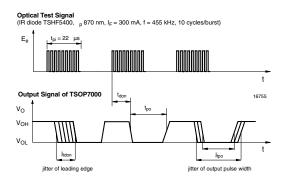


Figure 2. Output Fucntion (mit Jitter)

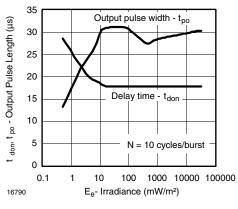


Figure 3. Output Pulse Diagram (t_{don}, t_{po})

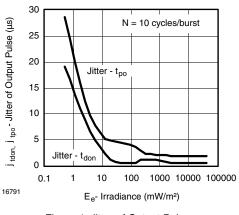


Figure 4. Jitter of Output Pulse

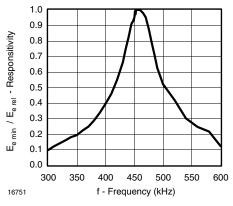


Figure 5. Frequency Dependence of Responsivity

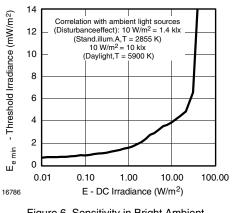
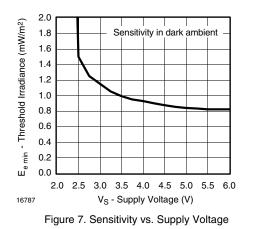


Figure 6. Sensitivity in Bright Ambient



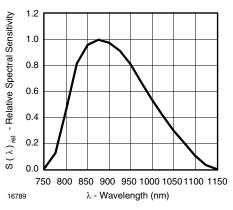
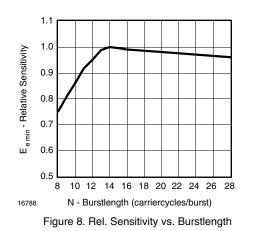
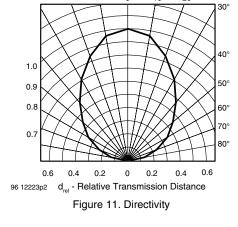


Figure 10. Relative Spectral Sensitivity vs. Wavelength

10

20





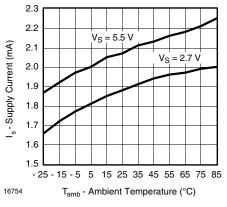


Figure 9. Supply Current vs. Ambient Temperature

TSOP7000

Vishay Semiconductors



Recommendation for Suitable Data Formats

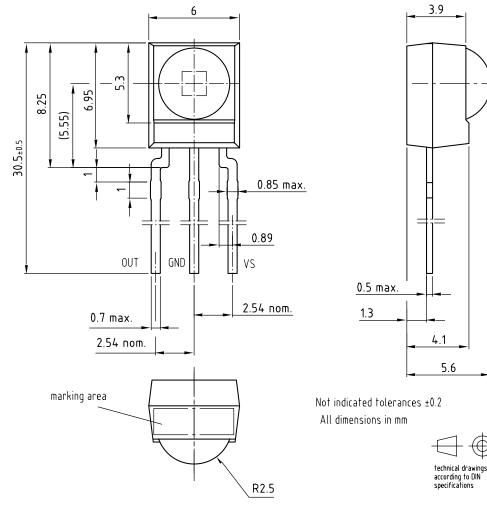
The circuit of the TSOP7000 is designed so that disturbance signals are identified and unwated output pulses due to noise or disturbances are avoided. A bandpass filter, an automatic gain control and an integrator stage is used to suppress such disturbances. The distinguishing marks between data signal and disturbance are carrier frequency, burst length and the envelope duty cycle.

The data signal should fullfill the following conditions:

• The carrier frequency should be close to 455 kHz.

Package Dimensions in millimeters

- The burstlength should be at least 22 μ s (10 cycles of the carrier signal) and shorter than 500 μ s.
- The separation time between two consecutive bursts should be at least 26 µs.
- If the data bursts are longer than 500 μs then the envelope duty cycle is limited to 25 %
- The duty cycle of the carrier signal (455 kHz) may be between 50 % (1.1 μ s pulses) and 10 % (0.2 μ s pulses). The lower duty cycle may help to save battery power.



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16003



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

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